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Kind regards,

Team Nexperia

# **PDTD113E series**

NPN 500 mA, 50 V resistor-equipped transistors;R1 = 1 k $\Omega$ , R2 = 1 k $\Omega$ Rev. 02 — 16 November 2009Pro

**Product data sheet** 

# 1. Product profile

#### 1.1 General description

500 mA NPN Resistor-Equipped Transistors (RET) family.

#### Table 1. Product overview

Type number	Package		PNP complement	
	NXP	JEITA	JEDEC	
PDTD113EK	SOT346	SC-59A	TO-236	PDTB113EK
PDTD113ES[1]	SOT54	SC-43A	TO-92	PDTB113ES
PDTD113ET	SOT23	-	TO-236AB	PDTB113ET

[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

#### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 500 mA output current capability

#### 1.3 Applications

- Digital application in automotive and industrial segments
- Controlling IC inputs

### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	50	V
lo	output current (DC)		-	-	500	mA
R1	bias resistor 1 (input)		0.7	1	1.3	kΩ
R2/R1	bias resistor ratio		0.9	1.0	1.1	



- Reduces component count
- Reduces pick and place costs
- ±10 % resistor ratio tolerance
- Cost saving alternative for BC817 series in digital applications
- Switching loads

# 2. Pinning information

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		2
3	GND (emitter)	001aab347	1 R2 R2 006aaa145
SOT54A			
1	input (base)		
2	output (collector)		2
3	GND (emitter)	1 2 001aab348	1 R2 006aaa145
SOT54 va	riant		
1	input (base)		
2	output (collector)		
3	GND (emitter)	Cm Cm D O01aab447	1 R2 006aaa 145
SOT23, S	OT346		
1	input (base)	_	
2	GND (emitter)	3	<u>ا ا</u> ع
3	output (collector)	12	1 R1 R2 sym007

# 3. Ordering information

ring informa	ation	
Package		
Name	Description	Version
SC-59A	plastic surface mounted package; 3 leads	SOT346
SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54
-	plastic surface mounted package; 3 leads	SOT23
	Package Name SC-59A	NameDescriptionSC-59Aplastic surface mounted package; 3 leadsSC-43Aplastic single-ended leaded (through hole) package; 3 leads

[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

# 4. Marking

#### Table 5.Marking codes

Type number	Marking code <sup>[1]</sup>
PDTD113EK	E1
PDTD113ES	D113ES
PDTD113ET	*7R

- [1] \* = -: made in Hong Kong
  - \* = p: made in Hong Kong
  - \* = t: made in Malaysia
  - \* = W: made in China

# 5. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	10	V
VI	input voltage				
	positive		-	+10	V
	negative		-	-10	V
lo	output current (DC)		-	500	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \leq 25 ~^{\circ}C$	<u>[1]</u>		
	SOT346		-	250	mW
	SOT54		-	500	mW
	SOT23		-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

# 6. Thermal characteristics

Table 7.	Thermal characteristics	6				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	[1]			
	SOT346		-	-	500	K/W
	SOT54		-	-	250	K/W
	SOT23		-	-	500	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

# 7. Characteristics

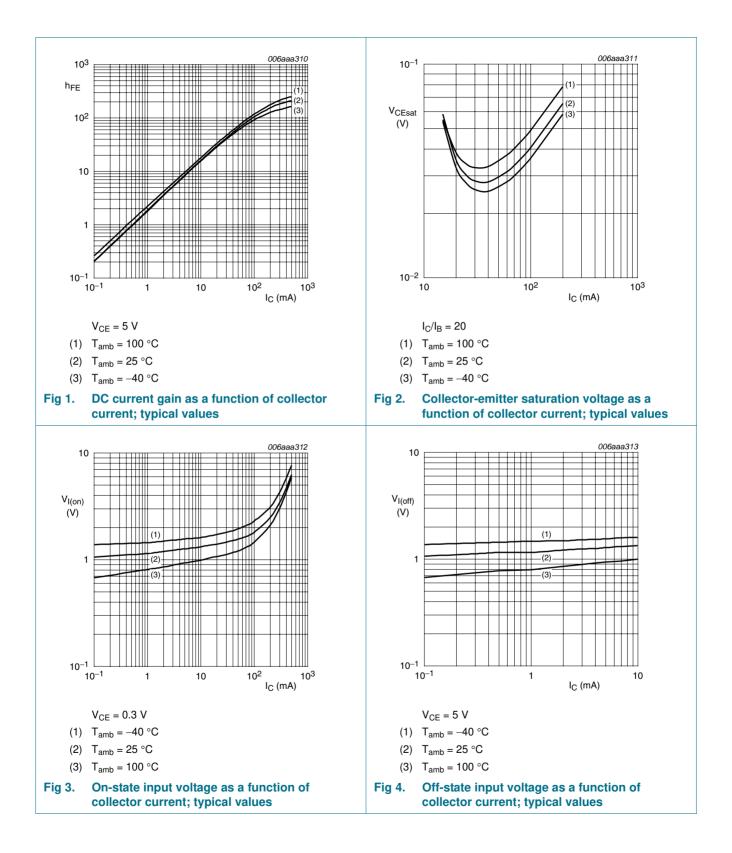
#### Table 8. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 40 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-	100	nA
	current	$V_{CB} = 50 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 50 \text{ V}; \text{ I}_{B} = 0 \text{ A}$	-	-	0.5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	4	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 50 \text{ mA}$	33	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = 50 \text{ mA}; I_{B} = 2.5 \text{ mA}$	-	-	0.3	V
V <sub>I(off)</sub>	off-state input voltage	$V_{CE}=5~V;~I_C=100~\mu A$	0.6	1.1	1.5	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE} = 0.3 \text{ V}; I_{C} = 20 \text{ mA}$	1.0	1.4	1.8	V
R1	bias resistor 1 (input)		0.7	1	1.3	kΩ
R2/R1	bias resistor ratio		0.9	1	1.1	
Cc	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = i <sub>e</sub> = 0 A; f = 100 MHz	-	7	-	pF

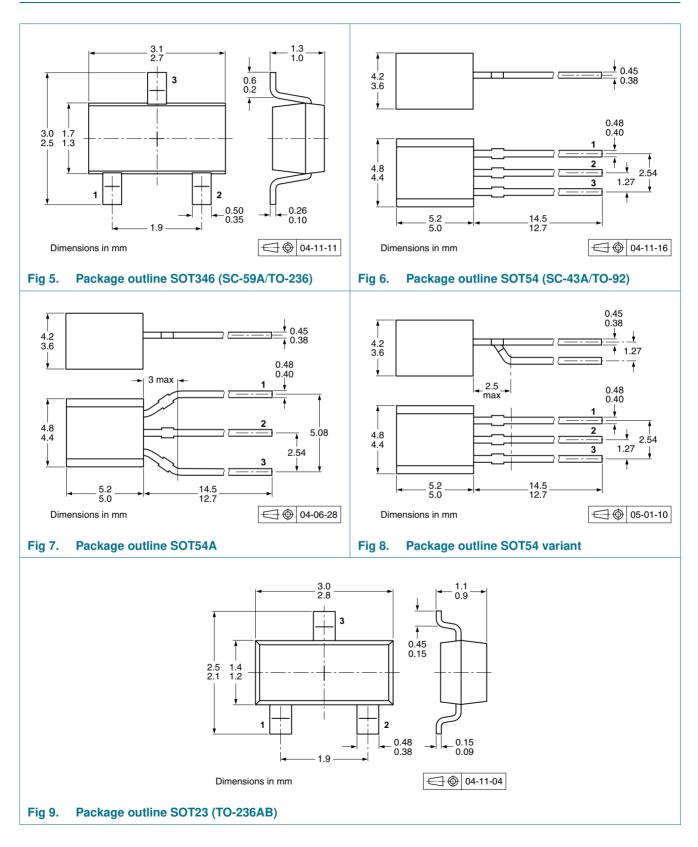
T<sub>amb</sub> = 25 °C unless otherwise specified.

# **PDTD113E series**

#### NPN 500 mA resistor-equipped transistors; R1 = 1 k $\Omega$ , R2 = 1 k $\Omega$



# 8. Package outline



# 9. Packing information

Type number	Package	Description	Packin	Packing quantity			
			3000	5000	10000		
PDTD113EK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135		
PDTD113ES	SOT54	bulk, straight leads	-	-412	-		
	SOT54A	tape and reel, wide pitch	-	-	-116		
		tape ammopack, wide pitch	-	-	-126		
	SOT54 variant	bulk, delta pinning	-	-112	-		
PDTD113ET	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235		

[1] For further information and the availability of packing methods, see Section 12.

# **10. Revision history**

Table 10. Revision h	istory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTD113E_SER_2	20091116	Product data sheet	-	PDTD113E_SER_1
Modifications:		eet was changed to reflect w legal definitions and disc		
PDTD113E_SER_1	20050414	Product data sheet	-	-

# **11. Legal information**

#### 11.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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